# **()** IDT.

# LOW-VOLTAGE 24-BIT BUS EXCHANGE SWITCH

#### FEATURES:

- 5Ω A/B bi-directional switch
- Isolation Under Power-Off Conditions
- Over-voltage tolerant
- Latch-up performance exceeds 100mA
- Vcc = 2.3V 3.6V, normal range
- ESD >2000V per MIL-STD-883, Method 3015; >200V using machine model (C = 200pF, R = 0)
- · Available in TSSOP package

# **DESCRIPTION:**

The CBTLV16212 provides a set of 24 high-speed switches for bus exchanging and switching. The device has low ON resistance, resulting in under 250ps propagation delay through the switch. The CBTLV16212 operates as a single 24-bit bus switch or as a 12-bit bus exchanger, which provides data exchanging between the four signal ports through the data select (S0-S2) pins.

The CBTLV16212 has the break-before-make feature, which allows zero current when switching between ports B1 and B2.

### **APPLICATIONS:**

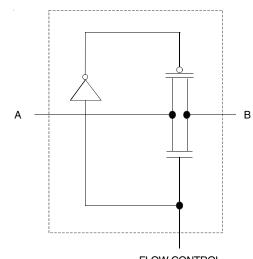
• 3.3V High Speed Bus Switching and Bus Isolation

# FUNCTIONAL BLOCK DIAGRAM

# 54 1B1 sw 1A1 SW sw 53 1A2 SW 1B: 27 SW 30 12B1 12A1 sw SW Т 29 12B2 28 SW 12A2

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# SIMPLIFIED SCHEMATIC, EACH SWITCH



FLOW CONTROL CIRCUITRY

DECEMBER 2014

#### **PIN CONFIGURATION**

|      |   |    | <i>۲ ر</i> |    |   |      |
|------|---|----|------------|----|---|------|
| S0   | Г | 1  | $\bigcirc$ | 56 |   | S1   |
| 1A1  | Г | 2  |            | 55 |   | S2   |
| 1A2  | Г | 3  |            | 54 | þ | 1B1  |
| 2A1  | Г | 4  |            | 53 | þ | 1B2  |
| 2A2  | Г | 5  |            | 52 | þ | 2B1  |
| 3A1  | Γ | 6  |            | 51 |   | 2B2  |
| 3A2  | Г | 7  |            | 50 |   | 3B1  |
| GND  | Γ | 8  |            | 49 |   | GND  |
| 4A1  | Г | 9  |            | 48 |   | 3B2  |
| 4A2  | Γ | 10 |            | 47 |   | 4B1  |
| 5A1  | Γ | 11 |            | 46 |   | 4B2  |
| 5A2  |   | 12 |            | 45 |   | 5B1  |
| 6A1  | Γ | 13 |            | 44 |   | 5B2  |
| 6A2  | Γ | 14 |            | 43 |   | 6B1  |
| 7A1  |   | 15 |            | 42 |   | 6B2  |
| 7A2  | Γ | 16 |            | 41 |   | 7B1  |
| Vcc  | Г | 17 |            | 40 |   | 7B2  |
| 8A1  | Γ | 18 |            | 39 |   | 8B1  |
| GND  |   | 19 |            | 38 |   | GND  |
| 8A2  |   | 20 |            | 37 |   | 8B2  |
| 9A1  | Γ | 21 |            | 36 |   | 9B1  |
| 9A2  | Γ | 22 |            | 35 |   | 9B2  |
| 10A1 | Γ | 23 |            | 34 |   | 10B1 |
| 10A2 | Г | 24 |            | 33 |   | 10B2 |
| 11A1 | Г | 25 |            | 32 | Þ | 11B1 |
| 11A2 | Γ | 26 |            | 31 | Þ | 11B2 |
| 12A1 | П | 27 |            | 30 | р | 12B1 |
| 12A2 | Г | 28 |            | 29 |   | 12B2 |
|      |   |    |            |    |   |      |

TSSOP TOP VIEW

#### ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

| Symbol | Description                   | Max.        | Unit |
|--------|-------------------------------|-------------|------|
| Vcc    | Supply Voltage Range          | -0.5 to 4.6 | V    |
| VI     | Input Voltage Range           | -0.5 to 4.6 | V    |
|        | Continuous Channel Current    | 128         | mA   |
| Ік     | Input Clamp Current, VI/O < 0 | -50         | mA   |
| Tstg   | Storage Temperature Range     | -65 to +150 | °C   |

NOTE:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

#### **PIN DESCRIPTION**

| Pin Names | Description              |
|-----------|--------------------------|
| Sx        | Data Select              |
| xAx       | Port A Inputs or Outputs |
| xBx       | Port B Inputs or Outputs |

#### **FUNCTION TABLE<sup>(1)</sup>**

| Inputs |    |    | Inputs/Outputs |    |                   |
|--------|----|----|----------------|----|-------------------|
| S2     | S1 | S0 | <b>A</b> 1     | A2 | Operation         |
| L      | L  | L  | Z              | Z  | Disconnect        |
| L      | L  | Н  | B1             | Z  | A1 port = B1 port |
| L      | Н  | L  | B2             | Z  | A1 port = B2 port |
| L      | Н  | Н  | Z              | B1 | A2 port = B1 port |
| Н      | L  | L  | Z              | B2 | A2 port = B2 port |
| Н      | L  | Н  | Z              | Z  | Disconnect        |
| Н      | Н  | L  | B1             | B2 | A1 port = B1 port |
|        |    |    |                |    | A2 port = B2 port |
| Н      | Н  | Н  | B2             | B1 | A1 port = B2 port |
|        |    |    |                |    | A2 port = B1 port |

NOTE:

1. H = HIGH Voltage Level L = LOW Voltage Level

Z = High-Impedance

#### **OPERATING CHARACTERISTICS**<sup>(1)</sup>

| Symbol | Parameter                        | Test Conditions    | Min. | Max. | Unit |
|--------|----------------------------------|--------------------|------|------|------|
| Vcc    | Supply Voltage                   |                    | 2.3  | 3.6  | V    |
| Vih    | High-Level Control Input Voltage | Vcc = 2.3V to 2.7V | 1.7  | —    | V    |
|        |                                  | Vcc = 2.7V to 3.6V | 2    | —    |      |
| Vil    | Low-Level Control Input Voltage  | Vcc = 2.3V to 2.7V | —    | 0.7  | V    |
|        |                                  | Vcc = 2.7V to 3.6V | —    | 0.8  |      |
| TA     | Operating Free-Air Temperature   |                    | -40  | +85  | °C   |

NOTE:

1. All unused control inputs of the device must be held at Vcc or GND to ensure proper device operation.

#### DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition:  $TA = -40^{\circ}C$  to +85°C

| Symbol             | Parameter                | Test Conditions   |                 | Min. | Тур. <sup>(1)</sup> | Max. | Unit |
|--------------------|--------------------------|---|-----------------|------|---------------------|------|------|
| Vik                | Control Inputs, Data I/O | Vcc = 3V, li = -18mA                                    |                 | _    | —                   | -1.2 | V    |
| li                 | Control Inputs           | Vcc = 3.6V, VI = Vcc or GNE                             | )               | _    | —                   | ±1   | μA   |
| loz                | Data I/O                 | Vcc = 3.6V, Vo = 0V or 3.6V                             | switch disabled | _    | —                   | 5    | μA   |
| loff               |                          | Vcc = 0V, VI or Vo = 0V or 3                            | .6V             | _    | —                   | 10   | μA   |
| lcc                |                          | Vcc = 3.6V, Io = 0, VI = Vcc                            | or GND          | _    | —                   | 10   | μA   |
| $\Delta ICC^{(2)}$ | Control Inputs           | Vcc = 3.6V, one input at 3V, other inputs at Vcc or GND |                 | _    | —                   | 300  | μA   |
| Сі                 | Control Inputs           | Vi = 3V or 0  |                 | _    | 5                   | _    | pF   |
| CIO(OFF)           |                          | Vo = 3V or 0 (switch off)                               |                 | _    | 13.5                | _    | pF   |
|                    | Max. at Vcc = 2.3V       | VI = 0  | Io = 64mA       | _    | 5                   | 8    |      |
|                    | Typ. at Vcc = 2.5V       |   | lo = 24mA       | —    | 5                   | 8    |      |
| Ron <sup>(3)</sup> |                          | VI = 1.7V   | lo = 15mA       | _    | 27                  | 40   | Ω    |
|                    |                          | VI = 0  | lo = 64mA       | _    | 5                   | 7    |      |
|                    | Vcc = 3V                 |   | lo = 24mA       | _    | 5                   | 7    |      |
|                    |                          | VI = 2.4V   | lo = 15mA       | _    | 10                  | 15   |      |

NOTES:

1. Typical values are at 3.3V, +25°C ambient.

2. The increase in supply current is attributable to each input that is at the specified voltage level rather than Vcc or GND.

3. This is measured by the voltage drop between the A and B terminals at the indicated current through the switch.

#### **SWITCHING CHARACTERISTICS**

|                    |                    | $Vcc = 2.5V \pm 0.2V$ |      | $Vcc = 3.3V \pm 0.3V$ |      |      |
|--------------------|--------------------|-----------------------|------|-----------------------|------|------|
| Symbol             | Parameter          | Min.                  | Max. | Min.                  | Max. | Unit |
| tPD <sup>(1)</sup> | Propagation Delay  | —                     | 0.15 | —                     | 0.25 | ns   |
|                    | A to B or B to A   |                       |      |                       |      |      |
| tep                | Propagation Delay  | 3                     | 11.1 | 3                     | 8.8  | ns   |
|                    | S to A or B        |                       |      |                       |      |      |
| ten                | Output Enable Time | 3                     | 10.9 | 3                     | 8.6  | ns   |
|                    | S to A or B        |                       |      |                       |      |      |
| tois               | OutputDisableTime  | 1                     | 8.7  | 2                     | 8.8  | ns   |
|                    | S to A or B        |                       |      |                       |      |      |

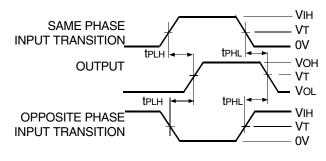
NOTE:

1. The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impededance).

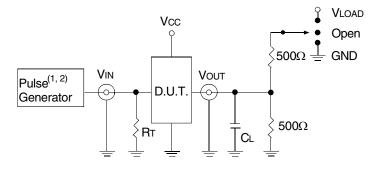
#### **TEST CIRCUITS AND WAVEFORMS**

#### **TEST CONDITIONS**

| Symbol | Vcc <sup>(1)</sup> =3.3V±0.3V | Vcc <sup>(2)</sup> =2.5V±0.2V | Unit |
|--------|-------------------------------|-------------------------------|------|
| VLOAD  | 6                             | 2 x Vcc                       | V    |
| Vih    | 3                             | Vcc                           | V    |
| Vτ     | 1.5                           | Vcc/2                         | V    |
| Vlz    | 300                           | 150                           | mV   |
| VHZ    | 300                           | 150                           | mV   |
| CL     | 50                            | 30                            | pF   |



Propagation Delay



#### Test Circuits for All Outputs

#### **DEFINITIONS:**

CL = Load capacitance: includes jig and probe capacitance.

RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.

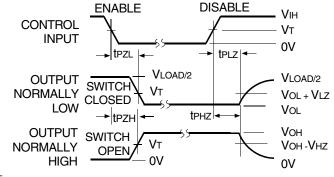
#### NOTES:

1. Pulse Generator for All Pulses: Rate  $\leq$  10MHz; tF  $\leq$  2.5ns; tR  $\leq$  2.5ns.

2. Pulse Generator for All Pulses: Rate  $\leq$  10MHz; tF  $\leq$  2ns; tR  $\leq$  2ns.

#### **SWITCH POSITION**

| Test      | Switch |
|-----------|--------|
| tplz/tpzL | VLOAD  |
| tpнz/tpzн | GND    |
| ted       | Open   |

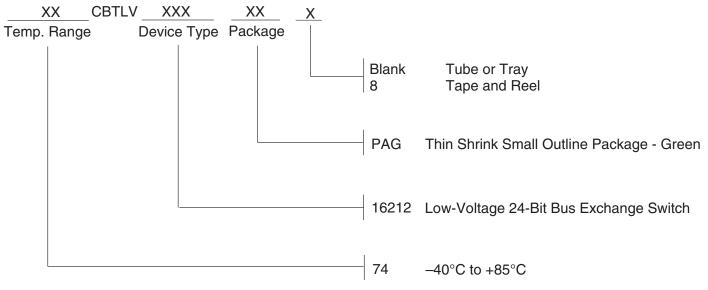


#### NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

#### Enable and Disable Times

#### **ORDERING INFORMATION**



#### **Datasheet Document History**

12/04/2014 Pg. 5 Updated the ordering information by removing the "IDT" notation, non RoHS part and by adding Tape and Reel information.



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